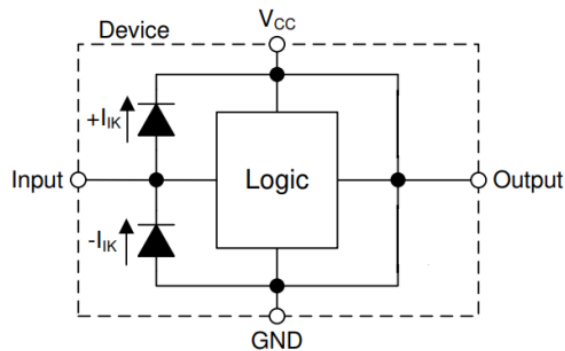


### FEATURES

- Operating Voltage Range: 1.65V to 5.5V
- Low Power Consumption: 1μA (Max)
- Operating Temperature Range: -40°C to +125°C
- Inputs Accept Voltage to 5.5V
- Output Drive: ±24mA at V<sub>CC</sub>=3.0V
- Micro Size Packages: SOT23-5, SC70-5
- Positive-negative input clamp diode



### APPLICATIONS

- AV Receiver
- Cable Modem Termination Systems
- Digital Picture Frame (DPF)
- High-Speed Data Acquisition and Generation
- Motor Controls: High-Voltage
- Personal Navigation Device (GPS)
- Portable Media Player
- Video Communication Systems

### DESCRIPTION

The single buffer is designed for 1.65V to 5.5V V<sub>CC</sub> operation. The GS1G125 device is single line driver with 3-state output. The output is disabled when the output-enable ( $\overline{OE}$ ) input is high.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor, the minimum value of the resistor is determined by the current-sinking capability of the driver.

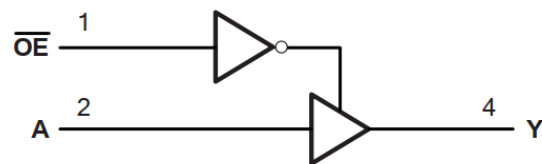
The GS1G125 is available in Green SOT23-5 and SC70-5 packages. It operates over an ambient temperature range of -40°C to +125°C.

### FUNCTION TABLE

INPUTS		OUTPUT
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

H=HIGH Logic Level  
L =LOW Logic Level  
X=Don't Care  
Z=High-impedance OFF-state

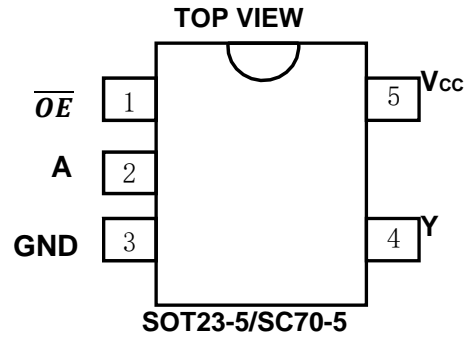
### Simplified Schematic



### PACKAGE/ORDERING INFORMATION

PRODUCT	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
GS1G125	GS1G125-TR	SOT23-5	Tape and Reel,3000	1G125
	GS1G125-CR	SC70-5	Tape and Reel,3000	1G125

## PIN CONFIGURATIONS



## PIN DESCRIPTION

PIN	NAME	I/O TYPE	FUNCTION
SOT23-5/SC70-5			
1	$\overline{OE}$	I	$\overline{OE}$ Enable/Input
2	A	I	Input
3	GND	-	Ground
4	Y	O	Output
5	V <sub>CC</sub>	-	Power pin

### Specifications

#### Absolute Maximum Ratings <sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted) <sup>(1)(2)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	-0.5	6.5	V
V <sub>I</sub>	Input voltage range <sup>(2)</sup>	-0.5	V <sub>CC</sub> +0.5	V
V <sub>O</sub>	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>	-0.5	6.5	V
V <sub>O</sub>	Voltage range applied to any output in the high or low state <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> <0	-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> <0	-50	mA
I <sub>O</sub>	Continuous output current		±50	mA
	Continuous current through V <sub>CC</sub> or GND		±100	mA
T <sub>J</sub>	Junction temperature	-65	150	°C
T <sub>stg</sub>	Storage temperature	-65	150	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V<sub>CC</sub> is provided in the Recommended Operating Conditions table.

#### ESD Ratings:

PARAMETER	SYMBOL		MAX	UNIT
Electrostatic discharge	I <sub>ESD</sub>	Latch up current	350	mA
	V <sub>ESD</sub>	Human-body model (HBM)	±5500	V
		Charge device model (CDM)	±2000	

#### Thermal Information:

THERMAL METRIC		GS1G125		UNIT
		SOT23-5	SC70-5	
R <sub>ΘJA</sub>	Junction-to-ambient thermal resistance	223.8	214.7	°C/W
R <sub>ΘJC(top)</sub>	Junction-to-case(top) thermal resistance	134.8	126.1	°C/W
R <sub>ΘJB</sub>	Junction-to-board thermal resistance	82.9	59.0	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	11.8	31.4	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	84.9	56.4	°C/W
R <sub>ΘJC(bot)</sub>	Junction-to-case(bottom) thermal resistance	N/A	N/A	°C/W

**ELECTRICAL CHARACTERISTICS**

 over recommended operating free-air temperature range (TYP values are at  $T_A = +25^\circ\text{C}$ , unless otherwise noted.) <sup>(1)</sup>
**Recommended Operating Conditions**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
Supply voltage	$V_{CC}$	Operating	1.65	5.5	V
		Data retention only	1.5	5.5	
High-level input voltage	$V_{IH}$	$V_{CC}=1.65\text{V to }1.95\text{V}$	$0.5 \times V_{CC}$		V
		$V_{CC}=2.3\text{V to }2.7\text{V}$	1.1		
		$V_{CC}=3\text{V to }3.6\text{V}$	1.3		
		$V_{CC}=4.5\text{V to }5.5\text{V}$	$0.4 \times V_{CC}$		
Low-level input voltage	$V_{IL}$	$V_{CC}=1.65\text{V to }1.95\text{V}$		$0.3 \times V_{CC}$	V
		$V_{CC}=2.3\text{V to }2.7\text{V}$		0.55	
		$V_{CC}=3\text{V to }3.6\text{V}$		0.75	
		$V_{CC}=4.5\text{V to }5.5\text{V}$		$0.2 \times V_{CC}$	
Input voltage	$V_I$		0	5.5	V
Output voltage	$V_O$		0	$V_{CC}$	V
Input transition rise or fall	$t_r, t_f$	$V_{CC}=1.8\text{V} \pm 0.15\text{V}, 2.5\text{V} \pm 0.2\text{V}$		20	ns/V
		$V_{CC}=3.3\text{V} \pm 0.3\text{V}$		10	
		$V_{CC}=5\text{V} \pm 0.5\text{V}$		5	
Operating temperature	$T_A$		-40	+125	$^\circ\text{C}$

**DC Characteristics**

PARAMETER	TEST CONDITIONS	$V_{CC}$	TEMP	MIN	TYP	MAX	UNITS	
$V_{OH}$	$I_{OH} = -100\mu\text{A}$	1.65V to 5.5V	Full	$V_{CC}-0.1$			V	
	$I_{OH} = -4\text{mA}$	1.65V		1.2				
	$I_{OH} = -8\text{mA}$	2.3V		1.7				
	$I_{OH} = -16\text{mA}$	3V		2.2				
	$I_{OH} = -24\text{mA}$			2.1				
	$I_{OH} = -32\text{mA}$	4.5V		3.3				
$V_{OL}$	$I_{OL} = 100\mu\text{A}$	1.65V to 5.5V	Full			0.1	V	
	$I_{OL} = 4\text{mA}$	1.65V				0.15		
	$I_{OL} = 8\text{mA}$	2.3V				0.25		
	$I_{OL} = 16\text{mA}$	3V				0.4		
	$I_{OL} = 24\text{mA}$					0.55		
	$I_{OL} = 32\text{mA}$	4.5V				0.55		
$I_I$	A or B inputs	$V_I=5.5\text{V or GND}$	5.5V		$\pm 0.1$	$\pm 1$	$\pm 1$	$\mu\text{A}$
$I_{off}$	$V_O=5.5\text{V}$	0	+25 C		$\pm 0.1$	$\pm 1$	$\mu\text{A}$	
			Full			$\pm 10$		
$I_{CC}$	$V_I=V_{CC} \text{ or GND}, I_O=0$	1.65V to 5.5V	+25 C		0.1	1	$\mu\text{A}$	
			Full			10		
$\Delta I_{CC}$	One input at $V_{CC}-0.6\text{V}$ , Other inputs at $V_{CC} \text{ or GND}$	3V to 5.5V	Full			500	$\mu\text{A}$	

### Switching Characteristics, $C_L=15\text{pF}$

over recommended operating free-air temperature range (-40°C to 125°C, unless otherwise noted.)<sup>(1)</sup>

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}=1.8\text{V}\pm 0.15\text{V}$	$V_{CC}=2.5\text{V}\pm 0.2\text{V}$	$V_{CC}=3.3\text{V}\pm 0.3\text{V}$	$V_{CC}=5\text{V}\pm 0.5\text{V}$	UNIT
			TYP	TYP	TYP	TYP	
$t_{pd}$	A	Y	6.3	4.3	3.5	2.6	ns

### Switching Characteristics, $C_L=30\text{pF}$ or $50\text{pF}$

over recommended operating free-air temperature range (-40°C to 125°C, unless otherwise noted.)<sup>(1)</sup>

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}=1.8\text{V}\pm 0.15\text{V}$	$V_{CC}=2.5\text{V}\pm 0.2\text{V}$	$V_{CC}=3.3\text{V}\pm 0.3\text{V}$	$V_{CC}=5\text{V}\pm 0.5\text{V}$	UNIT
			TYP	TYP	TYP	TYP	
$t_{pd}$	A	Y	10	7.7	6.8	6	ns
$t_{en}$	$\overline{OE}$	Y	9.8	7.4	6.6	5.8	ns
$t_{dis}$	$\overline{OE}$	Y	5.9	4.5	3.6	3	ns

### Operating Characteristics

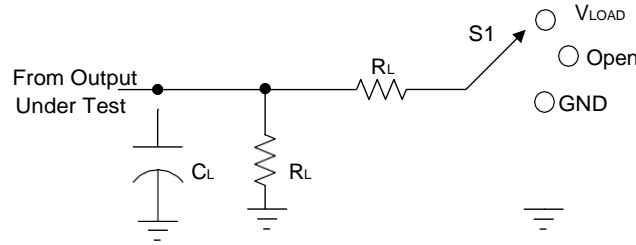
$T_A=25^\circ\text{C}$

PARAMETER			TEST CONDITION S	$V_{CC}=1.8\text{V}$	$V_{CC}=2.5\text{V}$	$V_{CC}=3.3\text{V}$	$V_{CC}=5\text{V}$	UNIT
				TYP	TYP	TYP	TYP	
$C_{pd}$	Power dissipation capacitance	Output enabled	f=10MHz	18	18	19	21	pF
		Output disabled		2	2	2	4	

(1) All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation.



### Parameter Measurement Information



TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND

$V_{CC}$	INPUTS		$V_M$	$V_{LOAD}$	$C_L$	$R_L$		$V_{\Delta}$
	$V_I$	$t_r/t_f$						
$1.8V \pm 0.15V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	1M $\Omega$	1k $\Omega$	0.15V
$2.5V \pm 0.2V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	1M $\Omega$	500 $\Omega$	0.15V
$3.3V \pm 0.3V$	3V	$\leq 2.5ns$	1.5V	6V	15pF	1M $\Omega$	500 $\Omega$	0.3V
$5V \pm 0.5V$	$V_{CC}$	$\leq 2.5ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	1M $\Omega$	500 $\Omega$	0.3V

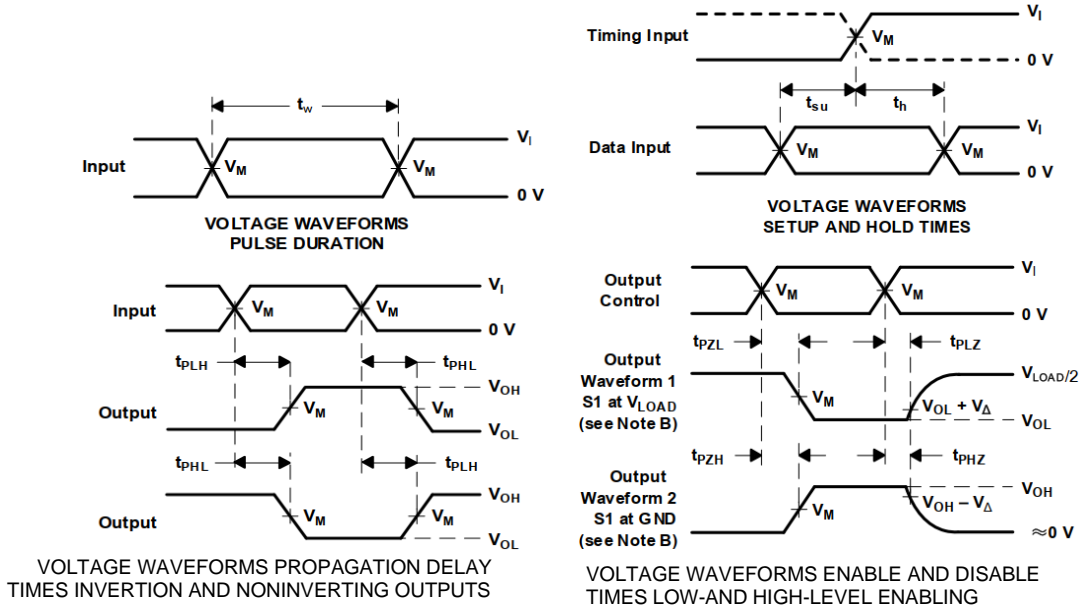


Figure 1. Load Circuit and Voltage Waveforms

Notes: A.  $C_L$  includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10$  MHz,  $Z_o = 50 \Omega$ .

D. The outputs are measured one at a time, with one transition per measurement.

E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .

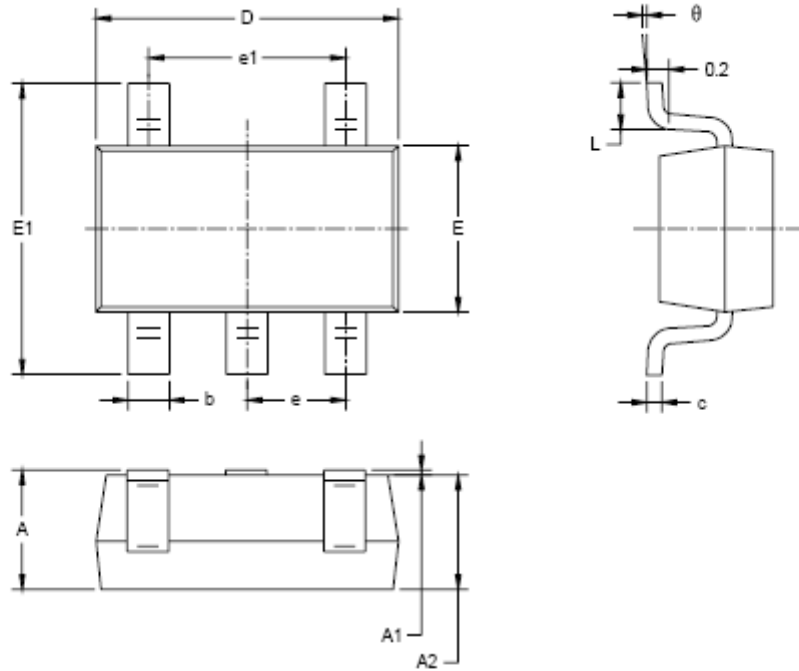
F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .

G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

H. All parameters and waveforms are not applicable to all devices.

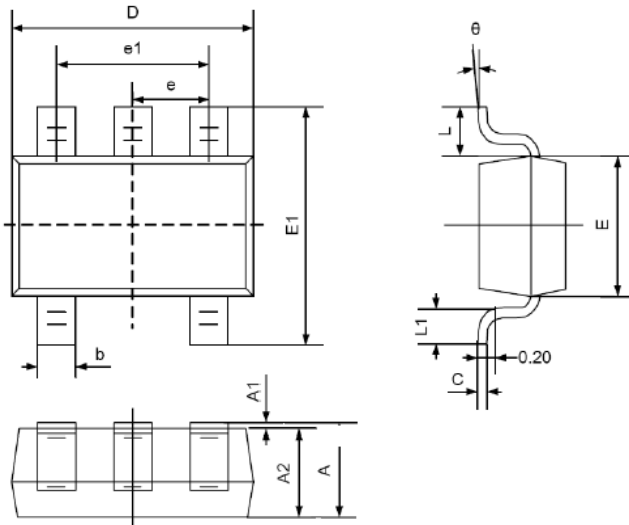
## PACKAGE OUTLINE DIMENSIONS

SOT23-5



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037 BSC	
e1	1.900 BSC		0.075 BSC	
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

SC70-5



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
C	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650TYP		0.026TYP	
e1	1.200	1.400	0.047	0.055
L	0.525REF		0.021REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°